GENERAL DESCRIPTION

Passivated, sensitive gate triacs in a plastic envelope, intended for use in general purpose bidirectional switching and phase control applications. These devices are intended to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

PINNING - TO220AB

PIN	DESCRIPTION	
1	main terminal 1	
2	main terminal 2	
3	gate	
tab	main terminal 2	

LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{drm}	Repetitive peak off-state voltages		-	-600D 600	V
T _(RMS)	RMS on-state current Non-repetitive peak on-state current	full sine wave; $T_{mb} \le 107$ °C full sine wave; $T_j = 25$ °C prior to surge	-	4	A
		t = 20 ms	-	25	A A
l ² t	I ² t for fusing	t = 16.7 ms t = 10 ms	-	27 3.1	A A ² s
dl _T /dt	Repetitive rate of rise of on-state current after	$I_{TM} = 6 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu\text{s}$	-	5.1	A 5
	triggering	T2+ G+	-	50	A/μs
		T2+ G-	-	50	A/µs
		T2- G- T2- G+	-	50 10	A/μs
lau	Peak gate current	12- 6+			A/μs Å
I _{GM} V _{GM}	Peak gate voltage		-	2 5 5	Ŷ
I P _{GM}	Peak gate power		-	5	W
P _{G(AV)} T _{stg} T _j	Average gate power Storage temperature Operating junction temperature	over any 20 ms period	- -40 -	0.5 150 125	°℃ ℃

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R _{th j-mb} R _{th j-a}	Thermal resistance junction to mounting base Thermal resistance junction to ambient	full cycle half cycle in free air		- - 60	3.0 3.7 -	K/W K/W K/W

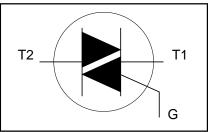
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{drm} I _{t(rms)} I _{tsm}	BT136- Repetitive peak off-state voltages RMS on-state current Non-repetitive peak on-state current	600D 600 4 25	V A A

PIN CONFIGURATION

tab

SYMBOL



BT136 series D

Product specification

Product specification

BT136 series D

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS		MIN.	TYP.	MAX.	UNIT
I _{GT}	Gate trigger current	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$					
01			T2+ G+	-	2.0	5	mA
			T2+ G-	-	2.5	5	mA
			T2- G-	-	2.5	5	mA
			T2- G+	-	5.0	10	mA
l I _L	Latching current	$V_{\rm D} = 12 \text{ V}; I_{\rm GT} = 0.1 \text{ A}$					
	-		T2+ G+	-	1.6	10	mA
			T2+ G-	-	4.5	15	mA
			T2- G-	-	1.2	10	mA
			T2- G+	-	2.2	15	mA
I _H	Holding current	$V_{\rm D} = 12 \text{ V}; \text{ I}_{\rm GT} = 0.1 \text{ A}$		-	1.2	10	mA
I _H V⊤	On-state voltage	$I_T = 5 A$		-	1.4	1.70	V
V _{GT}	Gate trigger voltage	$V_{\rm D} = 12 \text{ V}; I_{\rm T} = 0.1 \text{ A}$		-	0.7	1.5	V
		$V_{\rm D} = 400 \text{ V}; I_{\rm T} = 0.1 \text{ A}; T_{\rm L} = 125$	5 °C	0.25	0.4	-	V
I _D	Off-state leakage current	$V_{D}^{D} = 400 \text{ V}; I_{T} = 0.1 \text{ A}; T_{j} = 125$ $V_{D} = V_{DRM(max)}; T_{j} = 125 ^{\circ}\text{C}$		-	0.1	0.5	mA

DYNAMIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

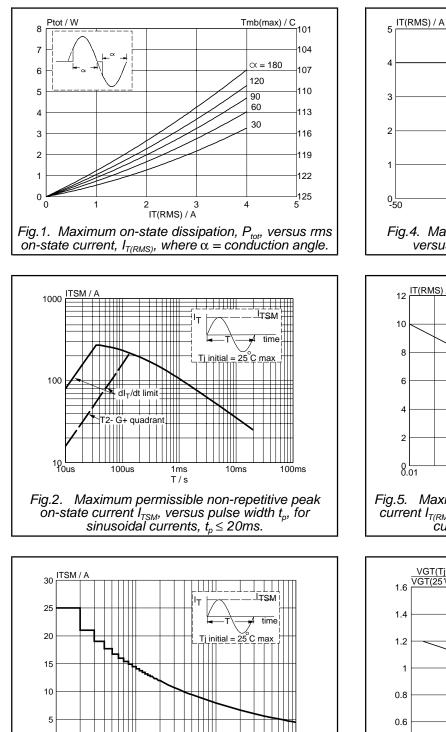
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
dV _D /dt	Critical rate of rise of off-state voltage	$V_{DM} = 67\% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; $R_{GK} = 1 k\Omega$	-	5	-	V/µs
t _{gt}		$I_{TM} = 6 \text{ A}; V_D = V_{DRM(max)}; I_G = 0.1 \text{ A};$ $dI_G/dt = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

BT136 series D

107℃

100

150

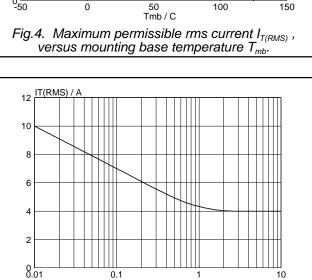


10 100 Number of cycles at 50Hz

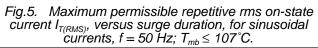
Fig.3. Maximum permissible non-repetitive peak

on-state current ITSM, versus number of cycles, for

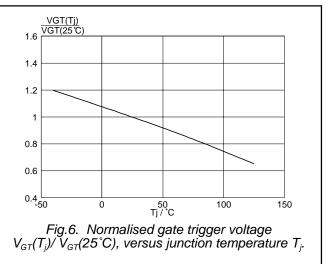
sinusoidal currents, f = 50 Hz.



0



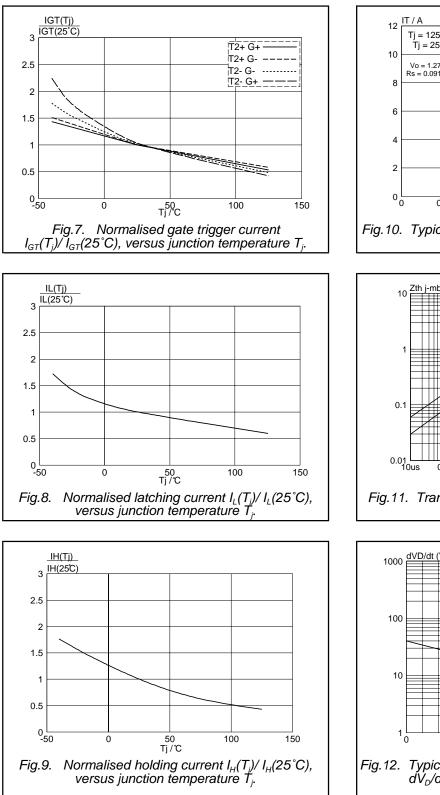
surge duration / s

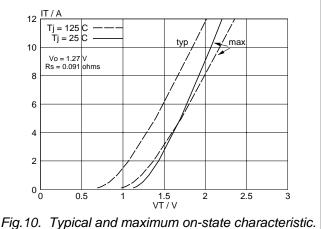


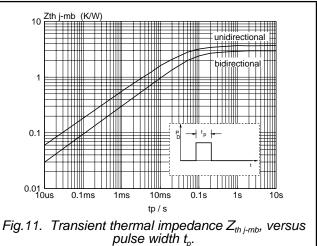
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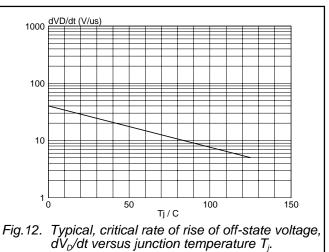
1000

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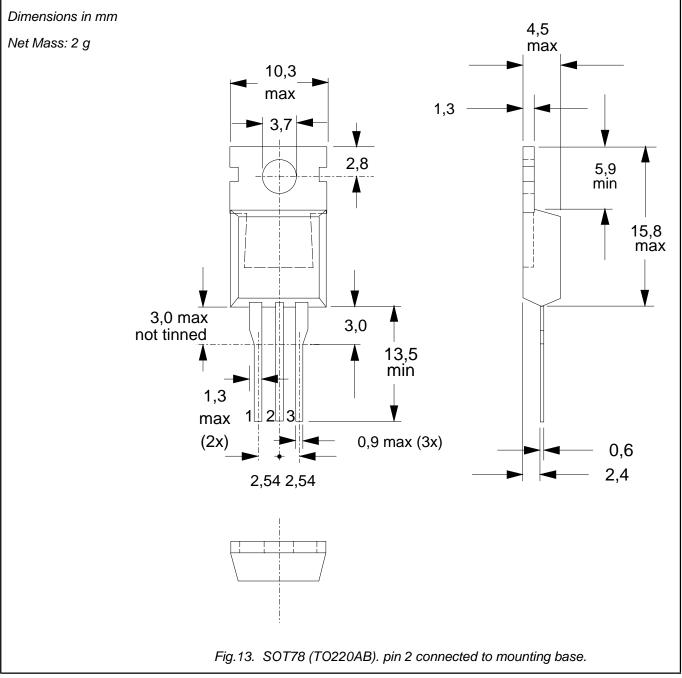






BT136 series D

MECHANICAL DATA



Notes 1. Refer to mounting instructions for SOT78 (TO220) envelopes. 2. Epoxy meets UL94 V0 at 1/8".

DEFINITIONS

DATA SHEET STATUS				
DATA SHEET STATUS ¹	PRODUCT STATUS ²	DEFINITIONS		
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice		
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in ordere to improve the design and supply the best possible product		
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A		
Limiting values	•	·		

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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² The product status of the device(s) described in this datasheet may have changed since this datasheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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